

JC-929 U.S. PTO
09/769576
01/25/01

ISSUE CLASSIFICATION	
Class	Subclass

O.I.P.E.		PATENT DATE
TR.		
SCANNED SB③	Q.A.	

APPLICATION NO. 09/769576	CONT/PRIOR F	CLASS 257	SUBCLASS 315	ART UNIT 2811	EXAMINER J. R. W. / Z. Zhou
------------------------------	-----------------	--------------	-----------------	------------------	--------------------------------

male

Method for manufacturing split-gate EEPROM memory cell and structure formed thereby *

PTO-2040
F-12/89

BEST AVAILABLE COPY

[illegible]

<input type="checkbox"/> TERMINAL DISCLAIMER	DRAWINGS <div> <div>Sheets Drwg.</div> <div>Figs. Drwg.</div> <div>Print Fig.</div> </div>		CLAIMS ALLOWED	
			Total Claims	Print Claim for O.G.
<input type="checkbox"/> The term of this patent subsequent to _____ (date) has been disclaimed.	<div> <div>_____ (Assistant Examiner)</div> <div>_____ (Date)</div> </div>		NOTICE OF ALLOWANCE MAILED	
<input type="checkbox"/> The term of this patent shall not extend beyond the expiration date of U.S. Patent. No. _____ <div>_____</div> <div>_____</div>			ISSUE FEE	
	<div> <div>_____ (Primary Examiner)</div> <div>_____ (Date)</div> </div>		Amount Due	Date Paid
<input type="checkbox"/> The terminal _____ months of this patent have been disclaimed.	<div> <div>_____ (Legal Instruments Examiner)</div> <div>_____ (Date)</div> </div>		ISSUE BATCH NUMBER	

The information disclosed herein may be restricted. Unauthorized disclosure may be prohibited by the United States Code Title 35, Sections 122, 181 and 368. Possession outside the U.S. Patent & Trademark Office is restricted to authorized employees and contractors only.

FILED WITH: ☐ DISK (CRF) ☐ FICHE ☐ CD-ROM
(Attached in pocket on right inside flap)

(FACE)